L Numb r	Hits	Search Text	DB	Time stamp
304	2	westra.in. and silicon and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/10 08:21
297	101	westra.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/10 08:21
-	2	("6008128").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:09
-	576	(359/223).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:14
-	255	(359/298).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:14
-	505	(359/838).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:14
-	88	(205/116).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:15
-	135	((359/223).CCLS.) and silicon$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 09:20
-	85	((359/298).CCLS.) and silicon$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:21
-	66	((359/838).CCLS.) and silicon$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:30

-	8	((205/116).CCLS.) and silicon$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:33
-	421	silicon and mirror and bulk and monolith$ and crystal$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:43
-	46	(silicon and mirror and bulk and monolith$ and crystal$4) and inlet and outlet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:37
-	31	silicon and mirror and bulk and monolith$ and (crystal$4 adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 10:51
-	89	(single adj crystal adj silicon) and mirror and (crystal$4 adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:08
-	692	(single adj crystal adj silicon) and mirror and plane and etch$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:43
-	309	((single adj crystal adj silicon) and mirror and plane and etch$3) and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:09
-	101	(((single adj crystal adj silicon) and mirror and plane and etch$3) and anisotrop$) and fiber and optic$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:10
-	121	(single and crystal and silicon) and mirror and plane and etch$3 and anisotrop$ and fiber and optic$4 and internal$2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:11
-	256	single and crystal$4 and silicon and mirror and etch$3 and stripe and intersect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:25

-	118	(singl and crystal$4 and silicon and mirror and etch$3 and strip and intersect$4) and internal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 11:58
-	373	(single near crystal$4 near silicon) with mirror	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 12:05
-	39	((single near crystal$4 near silicon) with mirror) and (fiber near optic$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 12:06
-	3645	digital and mirror and device and silicon and crystal$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:12
-	168	(digital and mirror and device and silicon and crystal$4) and bulk and monolith$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:12
-	341	silicon and mirror and etch$3 and stripe and intersect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:36
-	2259	silicon and mirror and pattern$3 and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 14:37
-	403	(single adj crystal$4 adj silicon) and mirror and pattern$3 and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:20
-	0	(bulk with (single adj crystal$4 adj silicon)) and (mirror near pattern$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:22
-	20	silicon and (mirror near pattern$3) and (anisotrop$ near etch$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:34

-	16	silicon and ((mirror near pattern$3) with array$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:39
-	2585	(mirror with array$) and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:16
-	9	(mirror with array$) and (bulk with single with crystal$4 with silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:43
-	2	((mirror with array$) and silicon) and anisotrop$ and (bulk near crystal$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 15:44
-	2	monolithic adj bulk adj crystal adj silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:17
-	2	monolithic with bulk with crystal with silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:17
-	1586	monolithic and bulk and crystal and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:18
-	25	(monolithic and bulk and crystal and silicon) and (crystalline near plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:19
-	362	(monolithic and bulk and crystal and silicon) and (crystalline and plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:20
-	4	((monolithic and bulk and crystal and silicon) and (crystalline and plane)) and (micro?mirror or (micro adj mirror))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:20

-	109	((monolithic and bulk and crystal and silicon) and (crystallin and plane)) and mirror	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:41
-	4	silicon near mirror n ar array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:42
-	1415	digital near (micromirror or micro?mirror or (micro adj mirror)) near device	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 16:43
-	350	(digital near (micromirror or micro?mirror or (micro adj mirror)) near device) and silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:12
-	16	(digital near (micromirror or micro?mirror or (micro adj mirror)) near device) and (single adj crystal adj silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:14
-	3991	(mirror or reflect$) and (single adj crystal adj silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:16
-	240	((mirror or reflect$) and (single adj crystal adj silicon)) and bulk and monolith$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:42
-	148	anisotrop$ with silicon with array with etch$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 17:43
-	226	(anisotrop$ with silicon with process$) and (mirror or reflector)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:38
-	25	silicon and mirror and passage and (crystalline adj plane)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:42

-	42	(monolithic and bulk and crystal and silicon) and (mirror or reflector) and crystalline and plan and intersect$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/17 18:44
-	606	(359/223).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:15
-	290	(359/298).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:28
-	553	(359/838).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:27
-	88	(205/116).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:27
-	42	((359/223).CCLS.) and (mirror or reflector) and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:28
-	23	((359/298).CCLS.) and (mirror or reflector) and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:52
-	15	((359/838).CCLS.) and (mirror or reflector) and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:54
-	1	((205/116).CCLS.) and (mirror or reflector) and anisotrop$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/07 17:56
-	244	silicon and ((mirror or reflector) with anisotrop$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/10 08:20